NSN 5961-01-340-6285

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-340-6285 **Inclosure Material:** Metal **Overall Length:** 0.245 inches **Terminal Length:** Between 0.013 inches and 0.017 inches **Overall Height:** Between 0.066 inches and 0.080 inches **Overall Width:** 0.170 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Criticality Code Justification: Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source 1st transistor **Current Rating Per Characteristic:** 2.00 amperes drain current 1st transistor **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0